Supporting Information

Enhancing energy migration upconversion through migratory interlayer in core-shell-shell nanostructure towards latent fingerprinting

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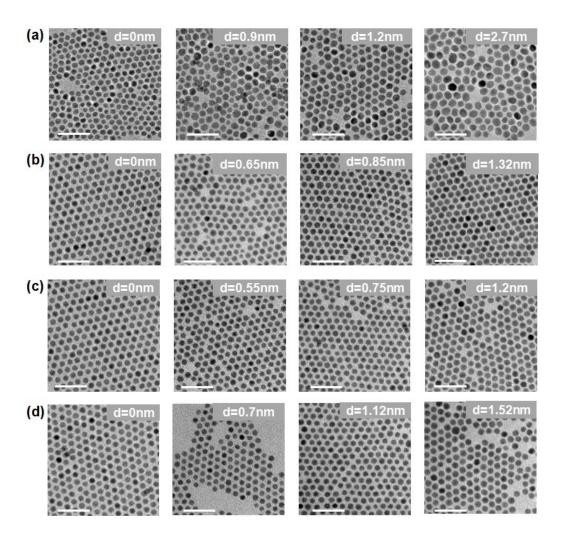


Figure S1. TEM images of the samples with a fine tuning of the NaGdF₄ interlayer thickness for various emitters: (a) Sm³⁺, (b) Nd³⁺, (c) Eu³⁺ and (d) Tb³⁺ in the outermost shell. The corresponding interlayer thickness "d" is given in the images. Scale bars, 50 nm.

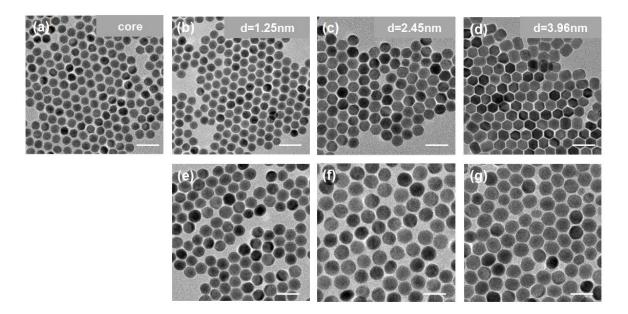


Figure S2. TEM images of NaGdF₄:Yb/Tm@NaGdF₄@NaGdF₄:Dy core-shell-shell nanoparticles with NaGdF₄ thickness of (b) 1.25 nm, (c) 2.45 nm, (d) 3.96 nm and their resultant core-shell-shell nanoparticles (e-g), respectively. Note that (a) shows the NaGdF₄:Yb/Tm core seeds for comparison. Scale bars, 100 nm.

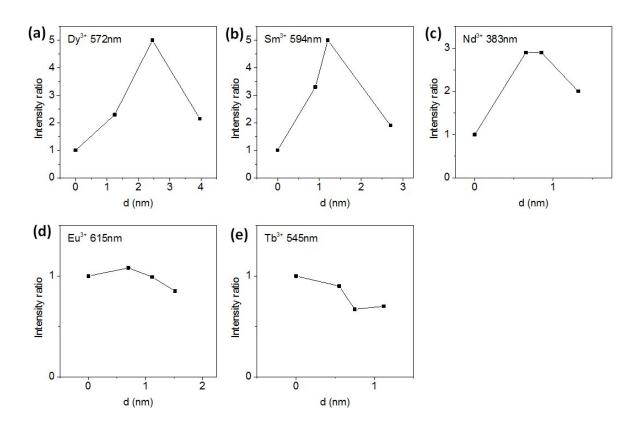


Figure S3. (a-e) Dependence of the typical upconversion emission intensity of (a) Dy^{3+} (572 nm), (b) Sm^{3+} (594 nm), (c) Nd^{3+} (383 nm), (d) Eu^{3+} (615 nm) and (e) Tb^{3+} (545 nm) on interlayer thickness for the NaGdF₄:Yb/Tm@NaGdF₄@NaGdF₄:A (A=Dy, Sm, Nd) coreshell-shell nanoparticles under 980 nm excitation, respectively.

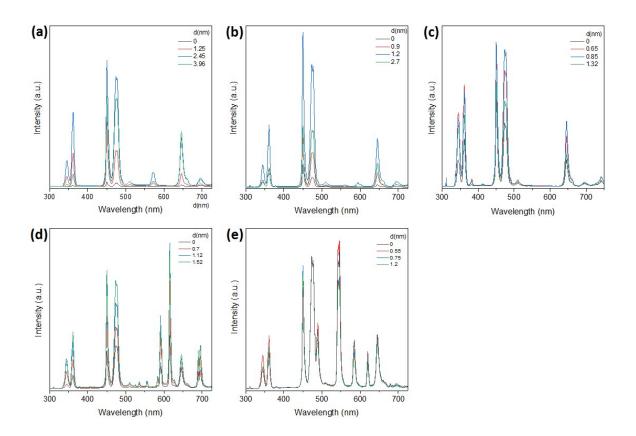


Figure S4. (a-e) Upconversion emission spectra recorded from the NaGdF₄:Yb/Tm@ NaGdF₄@NaGdF₄:A (A=Dy³⁺, Sm³⁺, Nd³⁺, Eu³⁺, Tb³⁺) core-shell-shell nanoparticles under 980 nm excitation.

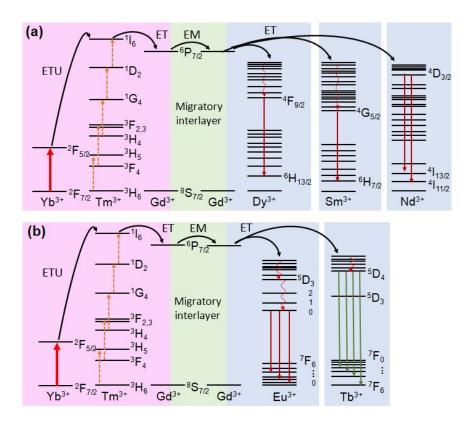


Figure S5. (a,b) Schematic of total energy transport process for photon upconversion in the NaGdF₄:Yb/Tm@NaGdF₄@NaGdF₄:A (A=Dy³⁺, Sm³⁺, Nd³⁺, Eu³⁺, Tb³⁺) core-shell-shell nanoparticles under 980 nm excitation.

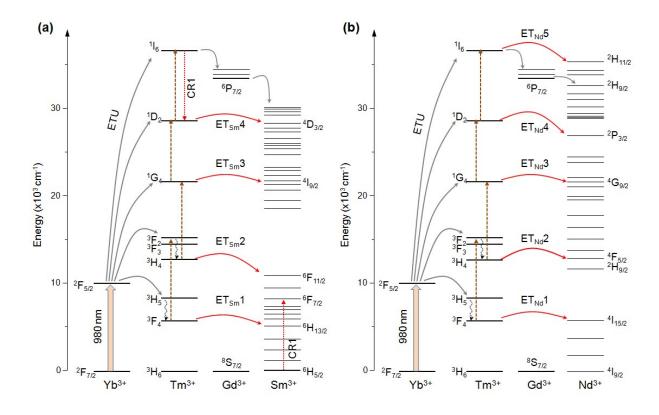


Figure S6. Schematic of possible quenching processes bewteen Tm³⁺ and the emitters of (a) Sm³⁺ and (b) Nd³⁺ at interfacial region in the NaGdF₄:Yb/Tm@NaGdF₄:A (A=Sm, Nd) coreshell nanoparticles under 980 nm excitation. Note that only the leading energy levels of the emitters are marked. ET_{Sm}1: Tm³⁺ (³F₄) → Sm³⁺ (⁶H_{13/2}), ET_{Sm}2: Tm³⁺ (³H₄) → Sm³⁺ (⁶F_{11/2}), ET_{Sm}3: Tm³⁺ (¹G₄) → Sm³⁺ (⁴I_{9/2}), ET_{Sm}4: Tm³⁺ (¹D₂) → Sm³⁺ (⁴D_{3/2}), CR1: [Tm³⁺ (¹I₆); Sm³⁺ (⁶H_{5/2})] → [Tm³⁺ (¹D₂); Sm³⁺ (⁶F_{7/2})]; ET_{Nd}1: Tm³⁺ (³F₄) → Nd³⁺ (⁴I_{15/2}), ET_{Nd}2: Tm³⁺ (³H₄) → Nd³⁺ (⁴F_{5/2},²H_{9/2}), ET_{Nd}3: Tm³⁺ (¹G₄) → Nd³⁺ (⁴G_{9/2}), ET_{Nd}4: Tm³⁺ (¹D₂) → Nd³⁺ (²P_{3/2}), ET_{Nd}5: Tm³⁺ (¹I₆) → Nd³⁺ (²H_{11/2}).

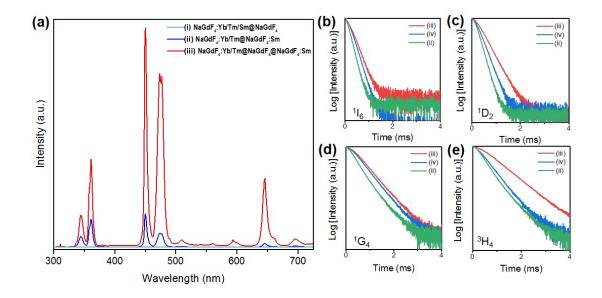


Figure S7. (a) Upconversion emission spectra of (i) NaGdF₄:Yb/Tm/Sm@NaGdF₄ and (ii) NaGdF₄:Yb/Tm@NaGdF₄:Sm core-shell and (iii) NaGdF₄:Yb/Tm@NaGdF₄@NaGdF₄:Sm core-shell-shell nanoparticles under 980 nm excitation. (b-e) The decay curves of Tm³⁺ at its ¹I₆ (at 350 nm), ¹D₂ (at 362 nm), ¹G₄ (at 475 nm) and ³H₄ (at 803 nm) states for the (iv) NaGdF₄:Yb/Tm@NaGdF₄ and (ii) NaGdF₄:Yb/Tm@NaGdF₄:Sm core-shell and (iii) NaGdF₄:Yb/Tm@NaGdF₄:MaGdF₄:Sm core-shell and (iii) NaGdF₄:Yb/Tm@NaGdF₄:Sm core-shell and (iii) NaGdF₄:Sm core-shell and (iii) NaGdF₄